



DCR1650C65

Phase Control Thyristor

DS5949-3 January 2014 (LN31253)

FEATURES

- **Double Side Cooling**
- **High Surge Capability**

KEY PARAMETERS

V _{DRM}	6500V
I _{T(AV)}	1650A
I _{TSM}	22000A
dV/dt*	1500V/µs
dl/dt	300A/µs

* Higher dV/dt selections available

APPLICATIONS

- **High Power Drives**
- High Voltage Power Supplies
- **Static Switches**

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{DRM} and V _{RRM} V	Conditions
DCR1650C65* DCR1650C60 DCR1650C55 DCR1650C50	6500 6000 5500 5000	$ \begin{array}{l} T_{vj} = -40^{\circ}C \text{ to } 125^{\circ}C, \\ I_{DRM} = I_{RRM} = 300\text{mA}, \\ V_{DRM}, V_{RRM} t_p = 10\text{ms}, \\ V_{DSM} \& V_{RSM} = \\ V_{DRM} \& V_{RRM} + 100V \\ \text{respectively} \end{array} $

Lower voltage grades available. * 6200V @ -40° C, 6500V @ 0° C

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DCR1650C65

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

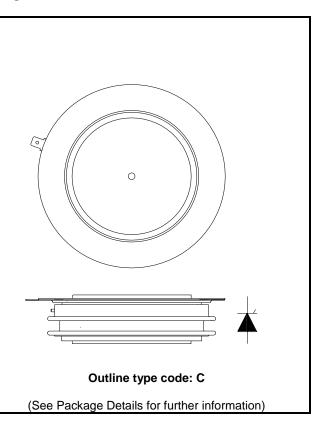


Fig. 1 Package outline



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CURRENT RATINGS

T_{case} = 60°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Sid	de Cooled			
I _{T(AV)}	Mean on-state current	Half wave resistive load		А
I _{T(RMS)}	RMS value	-		А
Ι _Τ	Continuous (direct) on-state current	-	2575	А

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{TSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 125^{\circ}C$	22.0	kA
l ² t	I ² t for fusing	$V_R = 0$	2.42	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.0101	°C/W
		Single side cooled	Anode DC	-	0.0176	°C/W
			Cathode DC	-	0.0239	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Clamping force 37kN	Double side	-	0.0025	°C/W
		(with mounting compound)	Single side	-	0.005	°C/W
T_{vj}	Virtual junction temperature	Blocking V _{DRM} / _{VRRM}		-	125	°C
T _{stg}	Storage temperature range			-55	125	°C
F _m	Clamping force			33	41	kN

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DYNAMIC CHARACTERISTICS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
I _{RRM} /I _{DRM}	Peak reverse and off-state current	At V _{RRM} /V _{DRM} , T _{case} = 125°C		-	300	mA
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V _{DRM} , T _j = 125°C, ga	ate open	-	1500	V/µs
dl/dt	Rate of rise of on-state current	From 67% V_{DRM} to 2x $I_{\text{T(AV)}}$	Repetitive 50Hz	-	150	A/µs
		Gate source 30V, 10Ω, t _r < 0.5μs, T _i = 125°C	Non-repetitive	-	300	A/µs
V _{T(TO)}	Threshold voltage – Low level	100A to 1500A at T _{case} = 128	5°C	-	1.0	V
	Threshold voltage – High level	1500A to 7200A at T _{case} = 125°C		-	1.2	V
r⊤	On-state slope resistance – Low level	100A to 1500A at T _{case} = 125°C		-	0.615	mΩ
	On-state slope resistance – High level	1500A to 7200A at T _{case} = 125°C		-	0.5	mΩ
t _{gd}	Delay time	V_D = 67% V_{DRM} , gate source 30V, 10 Ω t _r = 0.5µs, T _j = 25°C		-	3	μs
tq	Turn-off time	T_j = 125°C, V _R = 200V, dl/dt = 1A/µs, dV _{DR} /dt = 20V/µs linear		-	1200	μs
Qs	Stored charge	$I_T = 2000A, T_j = 125^{\circ}C, dI/dt - 1A/\mu s,$		2000	4500	μC
١L	Latching current	$T_j = 25^{\circ}C, V_D = 5V$		-	3	А
Ι _Η	Holding current	$T_j = 25^{\circ}C, R_{G-K} = \infty, I_{TM} = 500A, I_T = 5A$		-	300	mA

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GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V _{GT}	Gate trigger voltage	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	1.5	V
V_{GD}	Gate non-trigger voltage	At 50% V _{DRM} , T _{case} = 125°C	0.4	V
I _{GT}	Gate trigger current	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	350	mA
I _{GD}	Gate non-trigger current	At 50% V _{DRM} , T _{case} = 125°C	15	mA

CURVES

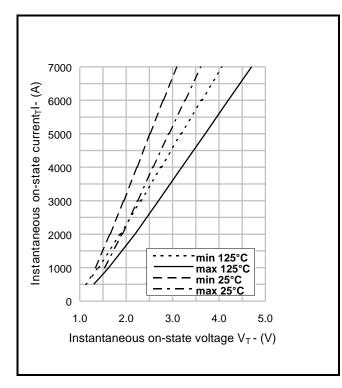
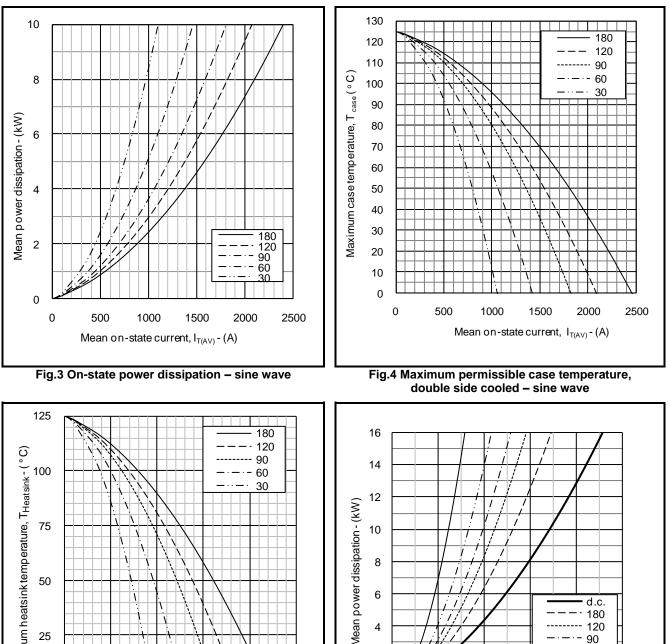


Fig.2 Maximum & minimum on-state characteristics

V_{TM} EQUATION

	Where	A = 0.666848
		B = 0.033446
V _{TM} = A + Bln (I _T) + C.I _T +D.√I _T		C = 0.000418
		D = 0.009666
	these va	alues are valid for $T_i = 125^{\circ}C$ for $I_T 100A$ to 7200A





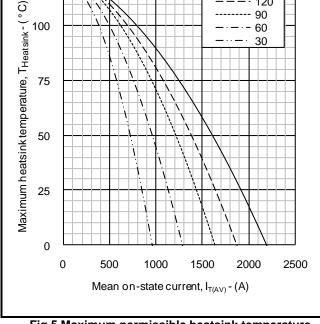


Fig.5 Maximum permissible heatsink temperature, double side cooled - sine wave



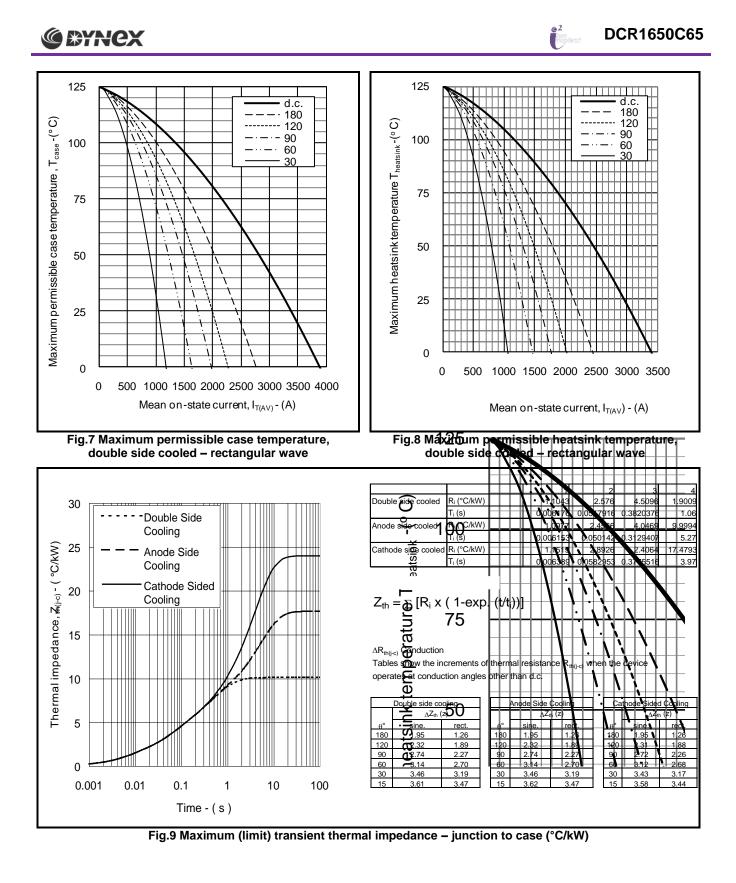
Mean on-state current, I_{T(AV)}- (A)

d.c.

·- 90

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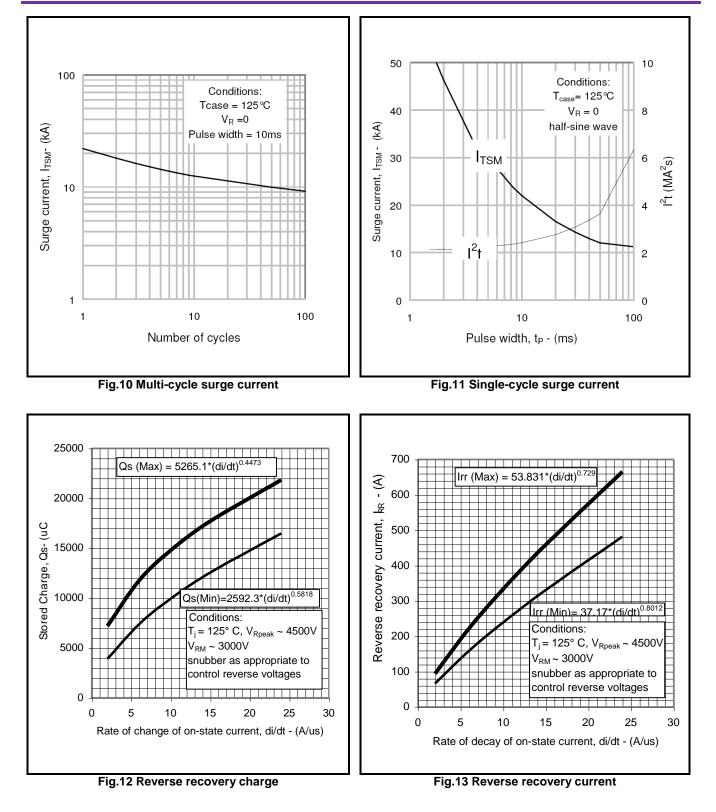
DCR1650C65



Servex (Construction)

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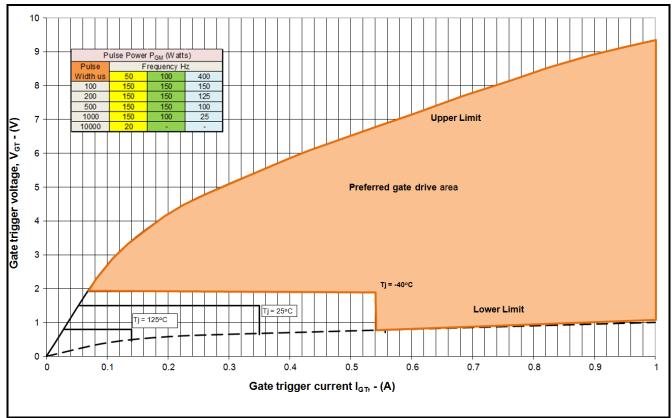


Fig14 Gate Characteristics

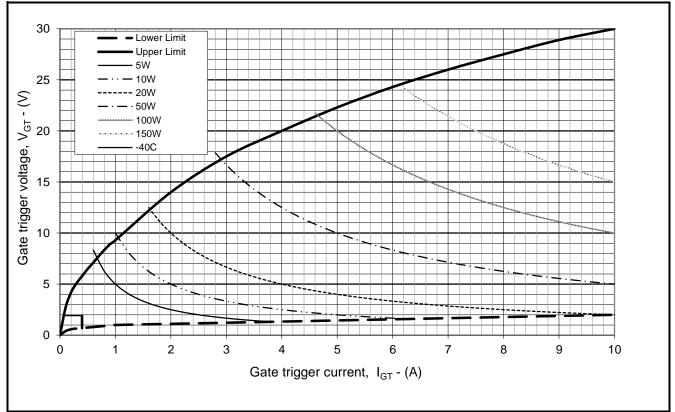


Fig. 15 Gate characteristics



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PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

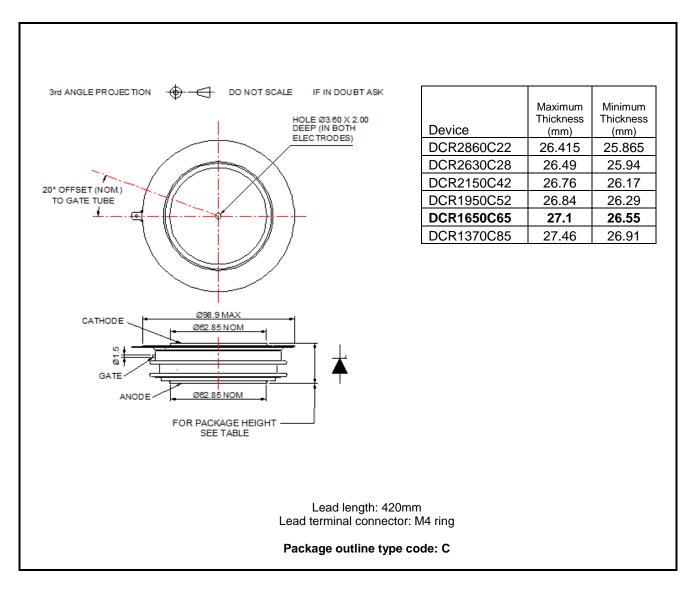


Fig.16 Package outline



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